## FAIRCHILD

SEMICONDUCTOR®

# 74VHCT04A Hex Inverter

#### **General Description**

The VHCT04A is an advanced high speed CMOS Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with  $V_{CC}=0V$ . These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

#### Features

High speed:  $t_{PD} = 4.7$  ns (typ) at  $T_A = 25^{\circ}C$ 

- High noise immunity:  $V_{IH} = 2.0V$ ,  $V_{IL} = 0.8V$
- Power down protection is provided on all inputs and outputs

June 1997

Revised February 2005

- Low noise: V<sub>OLP</sub> = 1.0V (max)
- Low power dissipation: I<sub>CC</sub> = 2 μA (max) @ T<sub>A</sub> = 25°C
- Pin and function compatible with 74HCT04

#### **Ordering Code:**

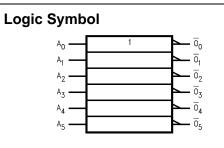
Order Number	Package Number	Package Description
74VHCT04AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHCT04AMX_NL (Note 1)	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHCT04ASJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT04AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT04AMTCX_NL (Note 1)	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT04AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74VHCT04ANX_NL (Note 1)	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

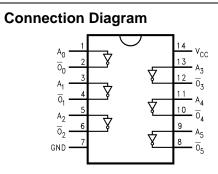
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

Note 1: "\_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Used this number to order device.

74VHCT04A





# **Pin Descriptions**

Pin Names	Description
A <sub>n</sub>	Inputs
0 <sub>n</sub>	Outputs

#### **Truth Table**

Α	ō
L	н
н	L

www.fairchildsemi.com

#### Absolute Maximum Ratings(Note 2)

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Input Voltage (VIN)	-0.5V to +7.0V
DC Output Voltage (V <sub>OUT</sub> )	
(Note 3)	-0.5V to V <sub>CC</sub> + 0.5V
(Note 4)	-0.5V to 7.0V
Input Diode Current (I <sub>IK</sub> )	–20 mA
Output Diode Current (I <sub>OK</sub> )	
(Note 5)	±20 mA
DC Output Current (I <sub>OUT</sub> )	±25 mA
DC V <sub>CC</sub> /GND Current (I <sub>CC</sub> )	±50 mA
Storage Temperature (T <sub>STG</sub> )	-65°C to +150°C
Lead Temperature (TL)	
(Soldering, 10 seconds)	260°C

#### Recommended Operating Conditions (Note 6)

Supply Voltage (V <sub>CC</sub> )	4.5V to +5.5V
Input Voltage (V <sub>IN</sub> )	0V to +5.5V
Output Voltage (V <sub>OUT</sub> )	
(Note 3)	0V to V <sub>CC</sub>
(Note 4)	0V to 5.5V
Operating Temperature (T <sub>OPR</sub> )	-40°C to +85°C
Input Rise and Fall Time $(t_r, t_f)$	
$V_{CC} = 5.0V \pm 0.5V$	0 ns/V ~ 20 ns/V

**74VHCT04A** 

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state.  $\mathbf{I}_{\text{OUT}}$  absolute maximum rating must be observed.

Note 4:  $V_{CC} = 0V$ .

Note 5:  $V_{OUT} < GND, \ V_{OUT} > V_{CC}$  (Outputs Active)

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

Symbol	Parameter	Vcc		$T_A = 25^{\circ}C$		$T_A = -40^{\circ}C$	C to +85°C	Units	6	nditions
Symbol Parameter	(V)	Min	Тур	Max	Min	Max	Units		nutions	
V <sub>IH</sub>	HIGH Level	4.5	2.0			2.0		V		
	Input Voltage	5.5	2.0			2.0		v		
V <sub>IL</sub>	LOW Level	4.5			0.8		0.8	V		
	Input Voltage	5.5			0.8		0.8	v		
V <sub>OH</sub>	HIGH Level	4.5	4.40	4.50		4.40		V	$V_{IN} = V_{IL}$	I <sub>OH</sub> = -50 μA
	Output Voltage	4.5	3.94			3.80		V		I <sub>OH</sub> = -8 mA
V <sub>OL</sub>	LOW Level	4.5		0.0	0.1		0.1	V	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 50 μA
	Output Voltage	4.5			0.36		0.44	V		I <sub>OL</sub> = 8 mA
I <sub>IN</sub>	Input Leakage Current	0 - 5.5			±0.1		±1.0	μA	V <sub>IN</sub> = 5.5V	or GND
I <sub>CC</sub>	Quiescent Supply Current	5.5			2.0		20.0	μA	$V_{IN} = V_{CC}$	or GND
I <sub>CCT</sub>	I <sub>CCT</sub> Maximum I <sub>CC</sub> /Input			1.35		1.50	mA	V <sub>IN</sub> = 3.4V		
		5.5			1.55		1.50	ША	Other Input	$ts = V_{CC} \text{ or } GND$
I <sub>OFF</sub>	Output Leakage Current	0.0			0.5		5.0	μA	V <sub>OUT</sub> = 5.5	1
	(Power Down State)	0.0			0.0		5.0	μΛ	*OUT - 3.3	v

### **Noise Characteristics**

Symbol	Parameter	Vcc	<b>T</b> <sub>A</sub> =	25°C	Units	Conditions	
Cymbol	r diamotor	(V)	Тур	Limits	onno		
V <sub>OLP</sub> (Note 7)	Quiet Output Maximum Dynamic V <sub>OL</sub>	5.0	0.8	1.0	V	C <sub>L</sub> = 50 pF	
V <sub>OLV</sub> (Note 7)	Quiet Output Minimum Dynamic V <sub>OL</sub>	5.0	-0.8	1.0	V	C <sub>L</sub> = 50 pF	
V <sub>IHD</sub> (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C <sub>L</sub> = 50 pF	
V <sub>ILD</sub> (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C <sub>L</sub> = 50 pF	

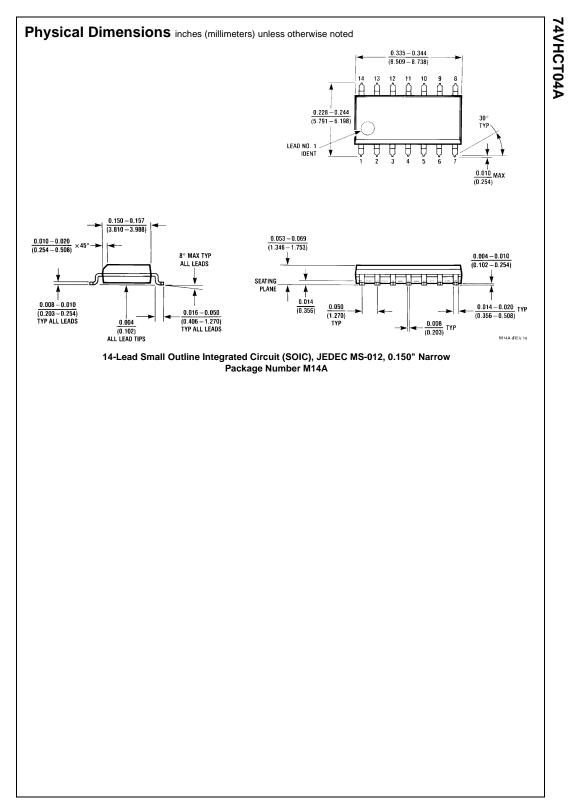
Note 7: Parameter guaranteed by design.

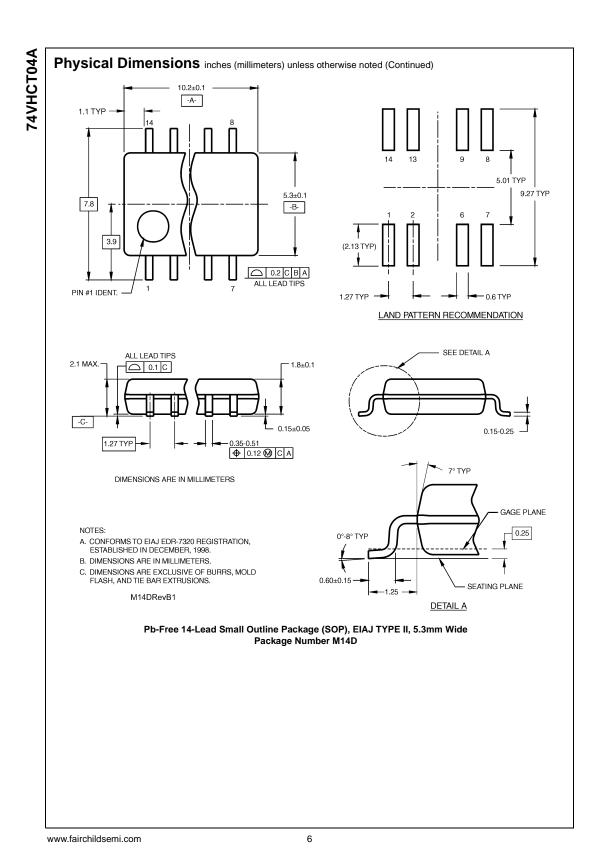
<
4
0
F
C
Ť
Σ
4
Ň

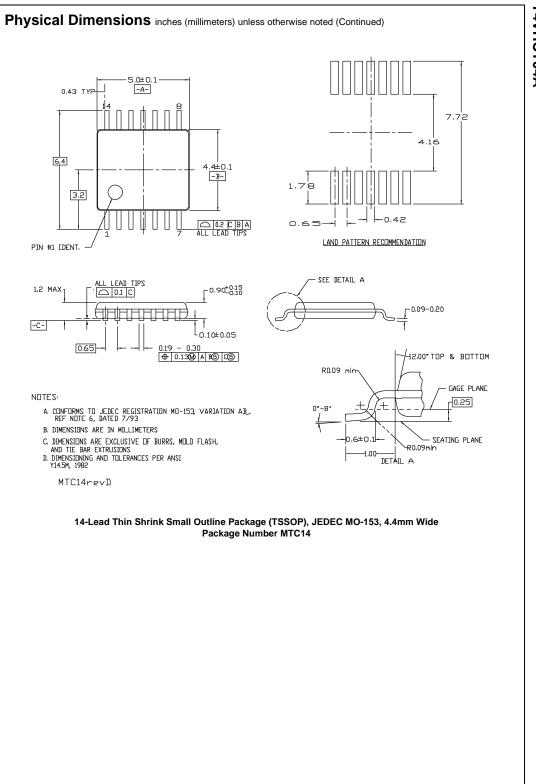
### **AC Electrical Characteristics**

Symbol Paramete	Parameter	V <sub>cc</sub>	$T_A = 25^{\circ}C$			$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C} \text{ to } +85^{\circ}\textbf{C}$		Units	Conditions
	i ulunotoi	(V)		Тур	Max	Min	Max	onno	Conditions
t <sub>PHL</sub>	Propagation Delay	$5.0 \pm 0.5$		4.7	6.7	1.0	7.5	ns	C <sub>L</sub> = 15 pF
t <sub>PLH</sub>		5.0 ± 0.5		5.5	7.7	1.0	8.5		C <sub>L</sub> = 50 pF
CIN	Input Capacitance			4	10		10	pF	V <sub>CC</sub> = OPEN
C <sub>PD</sub>	Power Dissipation			44					(Note 8)
	Capacitance			11				pF	

Note 8:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC}$  (opr.) =  $C_{PD} * V_{CC} * f_{1N} + I_{CC}/6$  (per gate).

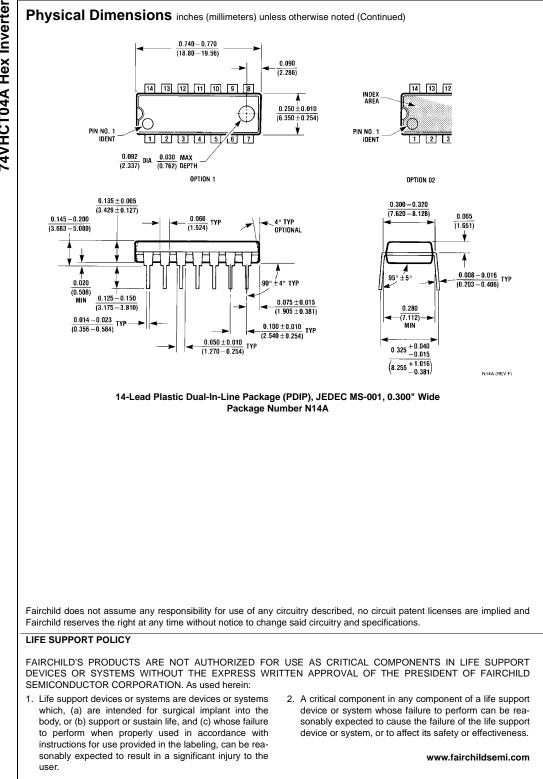






74VHCT04A

www.fairchildsemi.com



74VHCT04A Hex Inverter

www.fairchildsemi.com